### **DESCRIPTION**

The SPN3456 is the N-Channel logic enhancement mode power field effect transistors are produced using high cell density, DMOS trench technology.

This high density process is especially tailored to minimize on-state resistance.

These devices are particularly suited for low voltage application such as cellular phone and notebook computer power management and other battery powered circuits, and low in-line power loss are needed in a very small outline surface mount package.

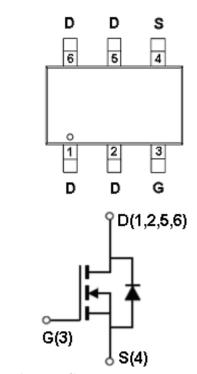
### **APPLICATIONS**

- Power Management in Note book
- Portable Equipment
- Battery Powered System
- DC/DC Converter
- Load Switch
- DSC
- LCD Display inverter

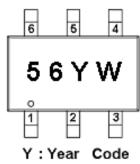
#### **FEATURES**

- 30V/6.0A, RDS(ON)=  $40m\Omega(a)V$ GS=10V
- 30V/5.0A, RDS(ON)=  $50m\Omega(a)$ VGS=4.5V
- ◆ Super high density cell design for extremely low RDS (ON)
- Exceptional on-resistance and maximum DC current capability
- ◆ SOT-23-6P package design

## PIN CONFIGURATION(SOP-23-6P)



# **PART MARKING**



W : Week Code

PIN	DES	CRIP'	TION

11, 22, 01111 1101,	II DEBOIN HOIT				
Pin	Symbol	Description			
1	D	Drain			
2	D	Drain			
3	G	Gate			
4	S	Source			
5	D	Drain			
6	D	Drain			

## **ORDERING INFORMATION**

Part Number	Part Number Package	
SPN3456S26RGB	SOT-23-6P	56YW

% Week Code : A ~ Z(1 ~ 26); a ~ z(27 ~ 52)

※ SPN3456S26RGB : Tape Reel ; Pb − Free; Halogen − Free

### **ABSOULTE MAXIMUM RATINGS**

(TA= $25^{\circ}$ C Unless otherwise noted)

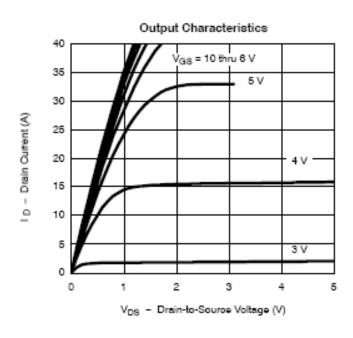
Parameter		Symbol	Typical	Unit	
Drain-Source Voltage		Vdss	30	V	
Gate –Source Voltage		VGSS	±20	V	
Continuous Dusin Comment(Tr-150°C)	TA=25°C	ID	6.0	Δ	
Continuous Drain Current(TJ=150°C)	Ta=70°C	ID	5.0	A	
Pulsed Drain Current		Ірм	30	A	
Continuous Source Current(Diode Conduct	tion)	Is	1.7	A	
Down Dissingtion	TA=25°C	D <sub>m</sub>	2.0	W	
Power Dissipation	Ta=70°C	PD	1.3	W	
Operating Junction Temperature		TJ	150	$^{\circ}\!\mathbb{C}$	
Storage Temperature Range		Tstg	-55/150	°C	
Thermal Resistance-Junction to Ambient		RθJA	90	°C/W	

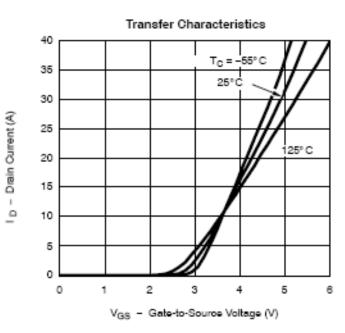
# **ELECTRICAL CHARACTERISTICS**

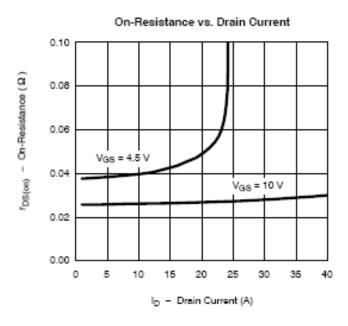
(Ta=25°C Unless otherwise noted)

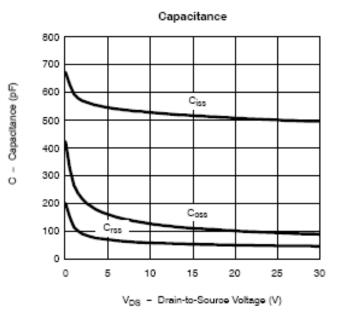
Parameter	Symbol	Conditions	Min.	Тур	Max.	Unit	
Static	<u>.</u>		•				
Drain-Source Breakdown Voltage	V(BR)DSS	VGS=0V,ID=250uA	30			V	
Gate Threshold Voltage	VGS(th)	VDS=VGS,ID=250uA	1.0		3.0 V	] <b>'</b>	
Gate Leakage Current	Igss	VDS=0V,VGS=±20V			±100	nA	
Zero Gate Voltage Drain Current	IDSS	VDS=24V,VGS=1.0V VDS=24V,VGS=0.0V TJ=55°C			1 10	uA	
On-State Drain Current	ID(on)	V <sub>DS</sub> ≥ 4.5V, V <sub>GS</sub> =4.5V	10			A	
Drain-Source On-Resistance	RDS(on)	VGS = 10V,ID=6.0A VGS =4.5V,ID=5.0A		0.030 0.040	0.040 0.050	Ω	
Forward Transconductance	gfs	VDS=4.5V,ID=5.4A		12		S	
Diode Forward Voltage	Vsd	Is=1.7A,VGS=0V		0.8	1.2	V	
Dynamic							
Total Gate Charge	Qg			10	18	nC	
Gate-Source Charge	Qgs	VDS=15VGS=10V ID=6.7A		1.6			
Gate-Drain Charge	Qgd	-ID=0.7A		3.2		1	
Input Capacitance	Ciss			450			
Output Capacitance	Coss	V <sub>DS</sub> =15V <sub>GS</sub> =0V f=1MHz		240		pF	
Reverse Transfer Capacitance	Crss			38			
T. O. T.	td(on)			7	15		
Turn-On Time	tr	VDD=15RL=15		10	20		
T. O.C. T.	td(off)	ID=1.0A,VGEN=10 RG=6Ω		20	40	ns	
Turn-Off Time	tf			11	20		

## TYPICAL CHARACTERISTICS

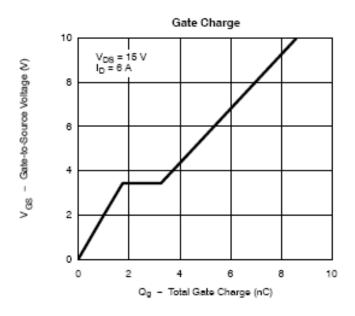


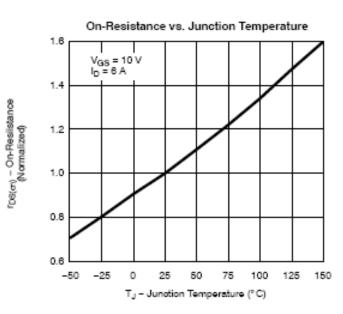


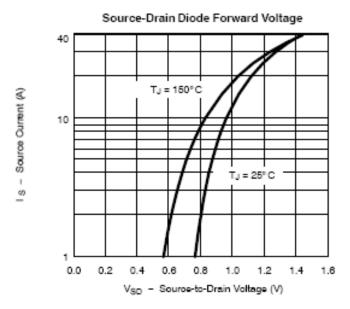


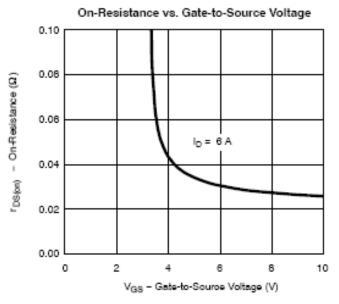


## TYPICAL CHARACTERISTICS

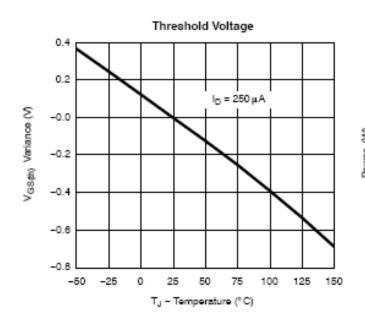


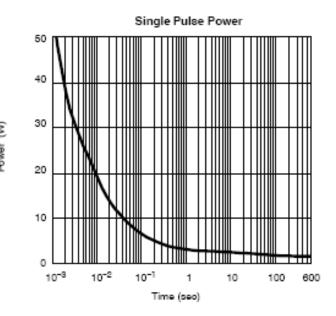




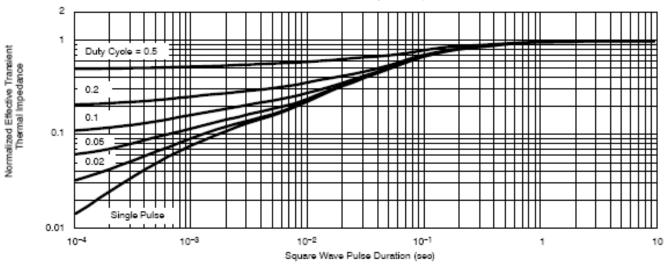


## TYPICAL CHARACTERISTICS



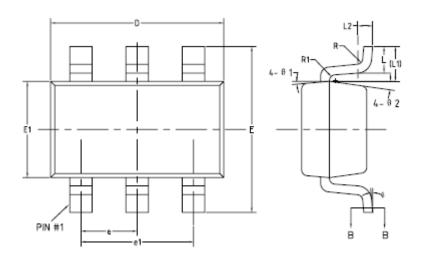


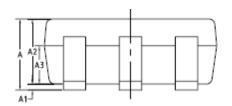
## Normalized Thermal Transient Impedance, Junction-to-Foot

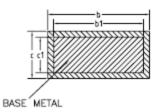




# SOT-23- 6P PACKAGE OUTLINE







COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX	
A	_	-	1.45	
A1	0	_	0.15	
A2	0.90	1.10	1.30	
A3	0.60	0.65	0.70	
b	0.39	-	0.49	
b1	0.38	0.40	0.45	
c	0.12	-	0.19	
c1	0.11	0.13	0.15	
D	2.85	2.95	3.05	
E	2.60	2.80	3.00	
E1	1.55	1.65	1.75	
e	0.85	0.95	1.05	
e1	1.80	1.90	2.00	
L	0.35	0.45	0.60	
L1		0.59REF		
L2	0.25BSC			
R	0.05	-	_	
R1	0.05	-	0.20	
θ	0.	-	8.	
θ1	8"	10°	12"	
θ 2	8.	10°	12"	

Information provided is alleged to be exact and consistent. SYNC Power Corporation presumes no responsibility for the penalties of use of such information or for any violation of patents or other rights of third parties which may result from its use. No license is granted by allegation or otherwise under any patent or patent rights of SYNC Power Corporation. Conditions mentioned in this publication are subject to change without notice. This publication surpasses and replaces all information previously supplied. SYNC Power Corporation products are not authorized for use as critical components in life support devices or systems without express written approval of SYNC Power Corporation.

© The SYNC Power logo is a registered trademark of SYNC Power Corporation
© 2004 SYNC Power Corporation – Printed in Taiwan – All Rights Reserved
SYNC Power Corporation
7F-2, No.3-1, Park Street
NanKang District (NKSP), Taipei, Taiwan, 115, R.O.C
Phone: 886-2-2655-8178

Fax: 886-2-2655-8468

© http://www.syncpower.com